

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

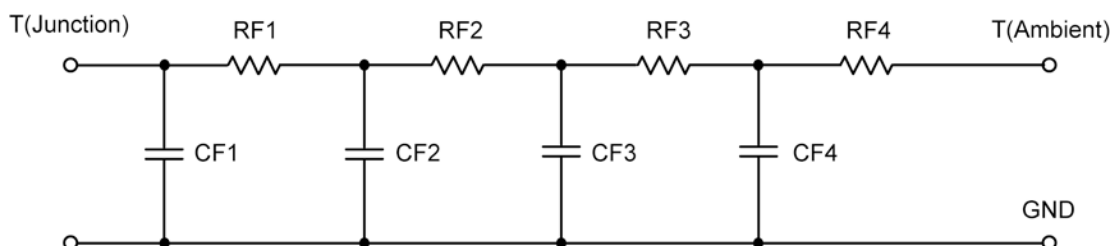
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	9.6744	210.0481 m	N/A
RT2	39.3627	342.2716 m	N/A
RT3	13.0119	279.3315 m	N/A
RT4	2.9510	468.3488 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	113.4016 m	2.7780 m	N/A
CT2	2.0969	16.5220 m	N/A
CT3	1.7672	31.3904 m	N/A
CT4	23.8769 m	21.5577 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	2.3468	338.0366 m	N/A
RF2	9.6654	419.7103 m	N/A
RF3	11.7567	427.4895 m	N/A
RF4	41.2311	114.7636 m	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	9.5175 m	1.9018 m	N/A
CF2	63.4848 m	5.1987 m	N/A
CF3	346.9739 m	2.1362 m	N/A
CF4	1.2254	31.8481 m	N/A

Note: NA indicates not applicable

